

#### **Smart Power High-Side-Switch** One Channel: 20 m $\Omega$

BTS441RG





### Overview

#### **General Description**

- N channel vertical power FET with charge pump, ground referenced CMOS compatible input, monolithically integrated in Smart SIPMOS technology
- Providing embedded protective functions
- Green Product (RoHS compliant)
- **AEC Qualified**

#### **Application**

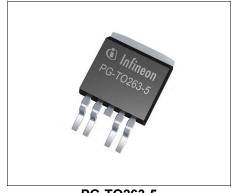
- μC compatible power switch 5 V, 12 V and 24 V DC applications
- All types of resistive, inductive and capatitive loads
- Most suitable for loads with high inrush currents, so as lamps
- Replaces electromechanical relays, fuses and discrete circuits

#### **Basic Functions**

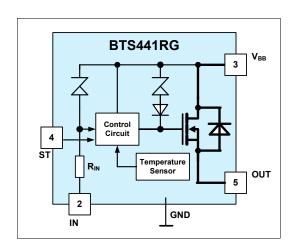
- Very low standby current
- Optimized static electromagnetic compatibility (EMC)
- μC and CMOS compatible
- Fast demagnetization of inductive loads
- Stable behavior at undervoltage

#### **Protection Functions**

- Short circuit protection
- **Current limitation**
- Overload protection
- Thermal Shutdown
- Overvoltage protection (including load dump) with external GND resistor
- Reverse battery protection with external GND-resistor
- Loss of ground and loss of  $V_{\mathrm{bb}}$  protection
- Electrostatic discharge (ESD) protection



PG-TO263-5



Туре	Package	Marking
BTS441RG	PG-TO263-5	BTS441R



Overview

### **Diagnostic Function**

- Diagnostic feedback with open drain output
- Open load detection in OFF-state
- · Feedback of thermal shutdown in ON-state

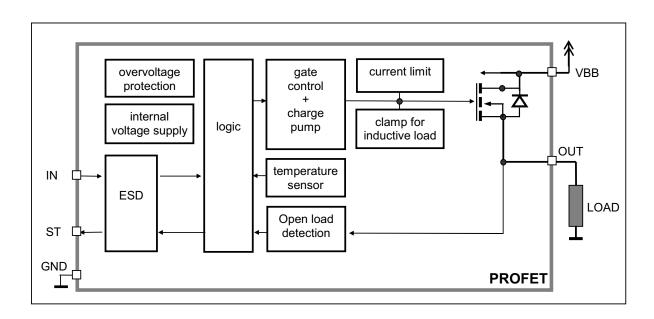
Product Summary		
Maximum on-state resistance at $T_j$ = 150 °C	$R_{DS(ON)}$	20 mΩ
Operating voltage	$V_{SOP}$	4.75 V 41 V
Nominal load current	I <sub>L (nom)</sub>	21 A
Current limitation	$I_{L(lim)}$	65 A

#### **Product Information**

Device Name	Status	Package	Pins	ECO status
BTS441RG	Active	PG-TO263-5	5	Green
BTS441RG	Discontinued	P-TO263-5	5	Gray
BTS441RS	Discontinued	P-TO220-5	5	Gray
BTS441RS	Discontinued	PG-TO220-5	5	Green



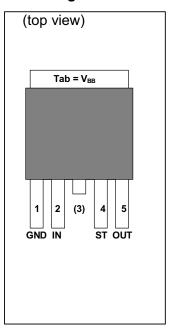
#### **Functional diagram**



#### **Pin Definitions and Functions**

Pin	Symbol	Function	
1	GND	Logic ground	
2	IN	Input, activates the power switch in case of logical high signal	
3	V <sub>bb</sub>	Positive power supply voltage The tab is shorted to pin 3	
4	ST	Diagnostic feedback, low on failure	
5	OUT	Output to the load	
Tab	V <sub>bb</sub>	Positive power supply voltage The tab is shorted to pin 3	

### Pin configuration





#### Maximum Ratings at T<sub>j</sub> = 25 °C unless otherwise specified

Parameter	Symbol	Values	Unit
Supply voltage (overvoltage protection see page 4)	$V_{ m bb}$	43	V
Supply voltage for full short circuit protection $T_{\text{j Start}}$ =-40+150°C	$V_{ m bb}$	34	V
Load dump protection <sup>1)</sup> $V_{\text{LoadDump}} = V_{\text{A}} + V_{\text{S}}, V_{\text{A}} = 13.5 \text{ V}$ $R_{\text{I}}^{2)} = 2 \Omega$ , $R_{\text{L}} = 0.5 \Omega$ , $t_{\text{d}} = 200 \text{ ms}$ , IN= low or high	V <sub>Load dump</sub> <sup>3)</sup>	60	V
Load current (Short-circuit current, see page 5)	<b>/</b> ∟	self-limited	Α
Operating temperature range	T <sub>j</sub> T <sub>stg</sub>	-40+150	°C
Storage temperature range	$T_{stg}$	-55+150	
Power dissipation (DC) ; TC≤25°C	$P_{tot}$	125	W
Maximal switchable inductance, single pulse $V_{bb}$ = 12V, $T_{j,start}$ = 150°C, $T_{C}$ = 150°C const. (see diagram, p.7) $I_{L(ISO)}$ = 21 A, RL= 0 Ω: $E^{4}$ <sub>AS</sub> =0.7J:	Z <sub>L</sub>	2.1	mH
Electrostatic discharge capability (ESD)  (Human Body Model)  Out to all other pins shorted:  acc. MIL-STD883D, method 3015.7 and  ESD assn. std. S5.1-1993; R=1.5kΩ; C=100pF	V <sub>ESD</sub>	1.0 4.0 8.0	kV
Input voltage (DC)	V <sub>IN</sub>	-10 +16	V
Current through input pin (DC) Current through status pin (DC) see internal circuit diagrams page 7	I <sub>IN</sub> I <sub>ST</sub>	±2.0 ±5.0	mA
Thermal resistance chip - case: junction - ambient (free air):	$R_{ ext{thJC}} \ R_{ ext{thJA}}$	≤ 1 ≤ 75	K/W
SMD version, device on pcb <sup>5</sup> ):		≤ 33	

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Supply voltages higher than  $V_{bb(AZ)}$  require an external current limit for the GND pin, e.g. with a 150  $\Omega$  resistor in the GND connection. A resistor for the protection of the input is integrated.

 $<sup>^{2)}</sup>$   $\,$   $\,$   $R_{\rm I}$  = internal resistance of the load dump test pulse generator

 $<sup>^{3)}</sup>$  V<sub>Load dump</sub> is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

<sup>4)</sup>  $E_{\rm AS}$  is the maximum inductive switch off energy

Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with 6cm $^2$  (one layer, 70 $\mu$ m thick) copper area for  $V_{bb}$  connection. PCB is vertical without blown air.



### **Electrical Characteristics**

Parameter and Conditions	Symbol	Values			Unit
at $T_j$ =-40+150°C, $V_{bb}$ = 12 V unless otherwise specified		min	typ	max	
Load Switching Capabilities and Characteristics	•				
On-state resistance (V <sub>bb</sub> (pin3) to OUT (pin5)); $I_L = 2 \text{ A V}_{bb} \ge 7\text{V}$ : $T_j = 25 \text{ °C}$ : $T_j = 150 \text{ °C}$ : see diagram page 9	R <sub>ON</sub>		15 28	20 37	mΩ
Nominal load current (pin 3 to 5) (ISO 10483-1, $6.7:V_{ON}=0.5V$ , $T_{C}=85$ °C	I <sub>L(ISO)</sub>	17	21		Α
Output current (pin 5) while GND disconnected or GND pulled up <sup>6)</sup> , V <sub>bb</sub> =30 V, V <sub>IN</sub> = 0, see diagram page 7	I <sub>L(GNDhigh)</sub>			2	mA
Turn-on time IN $\perp$ to 90% $V_{\text{OUT}}$ : Turn-off time IN $\perp$ to 10% $V_{\text{OUT}}$ : $R_{\text{L}}$ = 12 $\Omega$ ,	$t_{ m off}$	40 40	90 110	200 250	μs
Slew rate on 10 to 30% $V_{\text{OUT}}$ , $R_{\text{L}}$ = 12 $\Omega$ ,	dV/dt <sub>on</sub>	0.1		1	V/µs
Slew rate off 70 to 40% $V_{\text{OUT}}$ , $R_{\text{L}}$ = 12 $\Omega$ ,	-dV/dt <sub>off</sub>	0.1		1	V/μs
Operating Parameters					
Operating voltage $T_j$ =-40°C $T_j$ =+25°C $T_j$ =+105°C <sup>6)</sup> $T_j$ =+150°C	V <sub>bb(on)</sub>	4.75 4.75 4.75 5.0	  	41 43 43 43	V
Overvoltage protection <sup>7)</sup> $T_j = -40$ °C: $I_{bb} = 40$ mA $T_j = +25+150$ °C:	$V_{\rm bb(AZ)}$	41 43	 47	 52	V

 $T_i$ =-40...+25°C:

 $T_{j}$ =+105°C<sup>6</sup>):  $T_{j}$ =+150°C: I<sub>bb(off)</sub>

 $I_{L(off)}$ 

 $I_{\text{GND}}$ 

5

1.5

2

10

10

25

μΑ

μΑ

mΑ

6)	not subject to	production test,	specified by	design
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Off-State output current (included in Ibb(off))

Operating current (Pin 1)9), V<sub>IN</sub>=5 V,

Standby current (pin 3)8)

V<sub>IN</sub>=0 see diagram page 9

 $<sup>^{7)}~{\</sup>rm see}$  also  $V_{\rm ON(CL)}$  in table of protection functions and circuit diagram page 7

<sup>8)</sup> Measured with load, typ. 40 µA when no load in off

 $<sup>^{9)}</sup>$  Add  $\it I_{ST}, if \it I_{ST} > 0, add \it I_{IN}, if \it V_{IN} > 5.5 \, V$ 



Parameter and Conditions		Symbol		Values		Unit
at $T_j$ =-40+150°C, $V_{bb}$ = 12 V unless other	rwise specified		min	typ	max	
Protection Functions <sup>10)</sup>						
Current limit (pin 3 to 5)	<i>T</i> <sub>j</sub> =-40°C:	I <sub>L(lim)</sub>			85	Α
(see timing diagrams, page 9) $T_j = 25^{\circ}\text{C}$ : $T_i = +150^{\circ}\text{C}$ :			 40	65 		
Repetitive short circuit current limit		I <sub>L(SCr)</sub>		55		Α
$T_j = T_{jt}$ (see timing diagrams, page 10)						
Thermal shutdown time <sup>11)12)</sup>	T <sub>j,start</sub> =25°C:	$T_{\rm off(SC)}$		14		ms
(see timing diagram on page 10)						
Output clamp (inductive load switch off) at VOUT = Vbb - VON(CL), /L= 40 mA	; <i>T</i> <sub>j</sub> =-40°C: <i>T</i> <sub>j</sub> =25150°C:	V <sub>ON(CL)</sub>	41 43	 47	 52	V
Thermal overload trip temperature		$T_{\rm jt}$	150			°C
Thermal hysteresis		$\Delta T_{\rm jt}$		10		K
Reverse battery (pin 3 to 1) 13)		-V <sub>bb</sub>			32	V
Reverse battery voltage drop ( $V_{OUT} > I_L = -2A$	· V <sub>bb</sub> ) T <sub>j</sub> =+150°C:	-V <sub>ON(rev)</sub>		540		mV

<sup>10)</sup> Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

<sup>11)</sup> not subject to production test, specified by design

<sup>&</sup>lt;sup>12)</sup> Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with  $6\text{cm}^2$  (one layer,  $70\mu\text{m}$  thick) copper area for  $V_{bb}$  connection. PCB is vertical without blown air.

Requires 150  $\Omega$  resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Note that the power dissipation is higher compared to normal operating conditions due to the voltage drop across the intrinsic drain-source diode. The temperature protection is not active during reverse current operation! Input and Status currents have to be limited (see max. ratings page 1 and circuit page 7).



Parameter and Conditions	Symbol		Values	;	Unit
at $T_{\rm j}$ =-40+150°C, $V_{\rm bb}$ = 12 V unless otherwise specified		min	typ	max	
Diagnostic Characteristics					
Open load detection voltage <sup>14)</sup>	$V_{OUT(OL)}$	2	3	4	V
Input and Status Feedback <sup>15)</sup>					
Input resistance see circuit page 7	$R_{I}$	2.5	3.8	6.5	kΩ
Input turn-on threshold voltage	$V_{IN(T^+)}$	1.2		2.2	V
Input turn-off threshold voltage	$V_{IN(T-)}$	0.8		-	V
Input threshold hysteresis	$\Delta V_{\text{IN(T)}}$		0.3	-	V
Off state input current (pin 2) $V_{IN} = 0.4 \text{ V}$ :	I <sub>IN(off)</sub>	1		15	μΑ
On state input current (pin 2) $V_{IN} = 5 \text{ V}$ :	I <sub>IN(on)</sub>	4.5	12	24	μΑ
Delay time for status with open load after switch off (see timing diagrams, page 11),	t <sub>ST delay</sub>			500	μs
Status output (open drain)					_
Zener limit voltage $I_{ST} = +1.6 \text{ mA}$ : ST low voltage $I_{ST} = +1.6 \text{ mA}$ :	$V_{\rm ST(high)} \ V_{\rm ST(low)}$	5.4 	6.1 	0.4	<b>V</b>

#### **Truth Table**

	IN	OUT	ST
Normal operation	L	L	Н
	Н	Н	Н
Open load	L	Z	L <sup>16</sup> )
	н	н	Н
Short circuit to V <sub>bb</sub>	L	Н	L
	Н	Н	Н
Overtemperature	L	L	Н
	Н	L	L

L = "Low" Level H = "High" Level Z = high impedance, potential depends on external circuit Status signal valid after the time delay shown in the timing diagrams

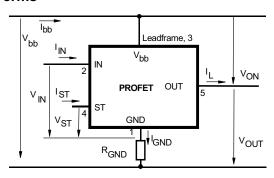
<sup>&</sup>lt;sup>14)</sup> External pull up resistor required for open load detection in off state

 $<sup>^{15)}\,\,</sup>$  If a ground resistor  $R_{GND}$  is used, add the voltage drop across this resistor.

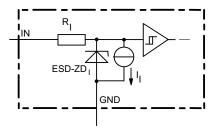
<sup>&</sup>lt;sup>16)</sup> L, if potential at the Output exceeds the OpenLoad detection voltage



#### **Terms**

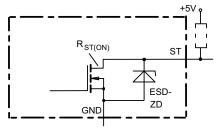


#### Input circuit (ESD protection)



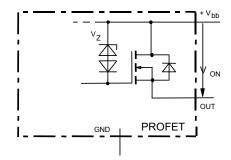
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

#### Status output



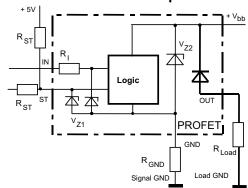
ESD-Zener diode: 6.1 V typ., max 5.0 mA;  $R_{ST(ON)}$  < 375  $\Omega$  at 1.6 mA, ESD zener diodes are not to be used as voltage clamp at DC conditions. Operation in this mode may result in a drift of the zener voltage (increase of up to 1 V).

#### Inductive and overvoltage output clamp



V<sub>ON</sub> clamped to 47 V typ.

#### Overvolt. and reverse batt. protection



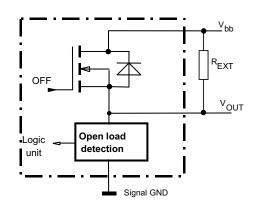
 $V_{Z1}$  = 6.1 V typ.,  $V_{Z2}$  = 47 V typ.,  $R_{GND}$  = 150 Ω,  $R_{ST}$ = 15 kΩ,  $R_{I}$ = 3.5 kΩ typ.

In case of reverse battery the load current has to be limited by the load. Temperature protection is not active

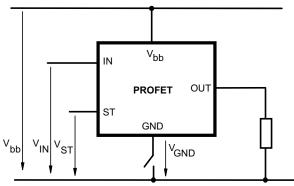
#### **Open-load detection**

OFF-state diagnostic condition:

Open Load, if V<sub>OUT</sub> > 3 V typ.; IN low



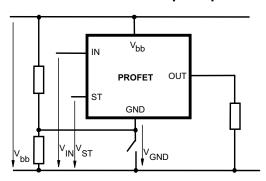
#### **GND** disconnect



Any kind of load. In case of Input=high is  $V_{OUT} \approx V_{IN}$  -  $V_{IN(T+)}$  .

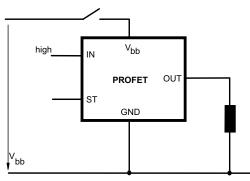


#### GND disconnect with GND pull up



Any kind of load. If  $V_{GND} > V_{IN} - V_{IN(T+)}$  device stays off Due to  $V_{GND} > 0$ , no  $V_{ST} =$  low signal available.

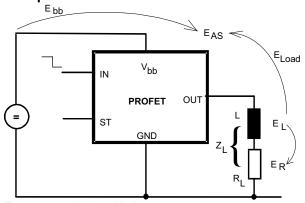
# V<sub>bb</sub> disconnect with charged inductive load



For inductive load currents up to the limits defined by  $Z_L$  (max. ratings and diagram on page 8) each switch is protected against loss of  $V_{bb}$ .

Consider at your PCB layout that in the case of Vbb disconnection with energized inductive load all the load current flows through the GND connection.

# Inductive load switch-off energy dissipation



Energy stored in load inductance:

$$E_L = \frac{1}{2} \cdot L \cdot I_1^2$$

While demagnetizing load inductance, the energy dissipated in PROFET is

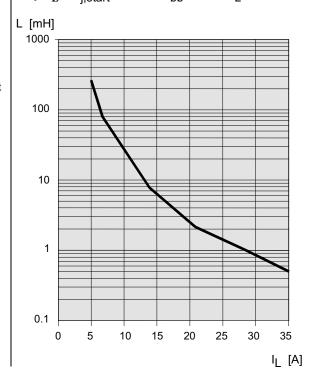
$$\textit{E}_{AS} = \textit{E}_{bb} + \textit{E}_{L} - \textit{E}_{R} = \ \, \textit{V}_{ON(CL)} \cdot \textit{i}_{L}(t) \; dt, \label{eq:ease_energy}$$

with an approximate solution for  $R_L > 0\,\Omega$ :

$$E_{\text{AS}} = \frac{I_{\text{L}} \cdot L}{2 \cdot R_{\text{L}}} \left( V_{\text{bb}} + |V_{\text{OUT(CL)}}| \right) \ ln \left( 1 + \frac{I_{\text{L}} \cdot R_{\text{L}}}{|V_{\text{OUT(CL)}}|} \right)$$

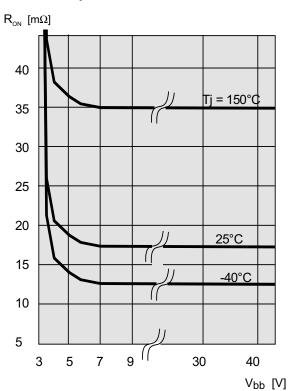
# Maximum allowable load inductance for a single switch off

$$L = f(I_L)$$
; T<sub>j,start</sub> = 150°C, V<sub>bb</sub> = 12 V, R<sub>L</sub> = 0  $\Omega$ 



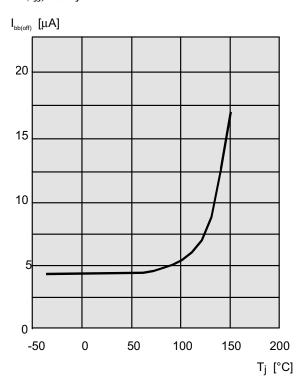


Typ. on-state resistance  $R_{ON} = f(V_{bb}, T_j)$ ; IL = 2 A, IN = high



### Typ. standby current

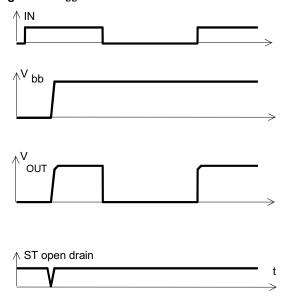
 $I_{bb(off)} = f(T_j)$ ;  $V_{bb} = 9...34 \text{ V}$ , IN1,2 = Iow





### **Timing diagrams**

Figure 1a: V<sub>bb</sub> turn on:



proper turn on under all conditions

**Figure 2a:** Switching a resistive load, turn-on/off time and slew rate definition:

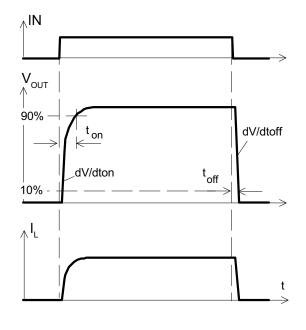


Figure 2b: Switching a lamp,

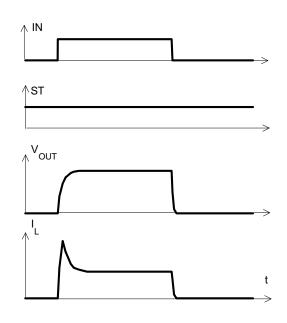


Figure 3a: Short circuit shut down by overtemperature, reset by cooling

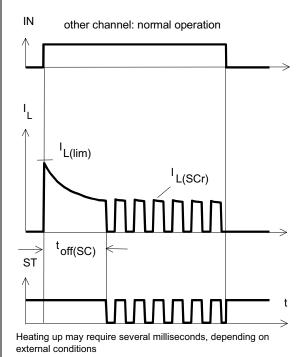




Figure 4a: Overtemperature: Reset if  $T_j < T_{jt}$ 

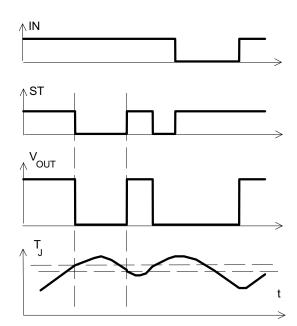
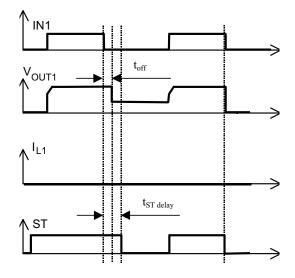


Figure 5a: Open load: detection in OFF-state, turn on/off to open load



 $t_{\mbox{\tiny ST delay}}.$  = 500µs Open load detection requires an external pull up resistor between OUT and  $V_{\mbox{\footnotesize{BB}}}$ 



### **Package Outlines**

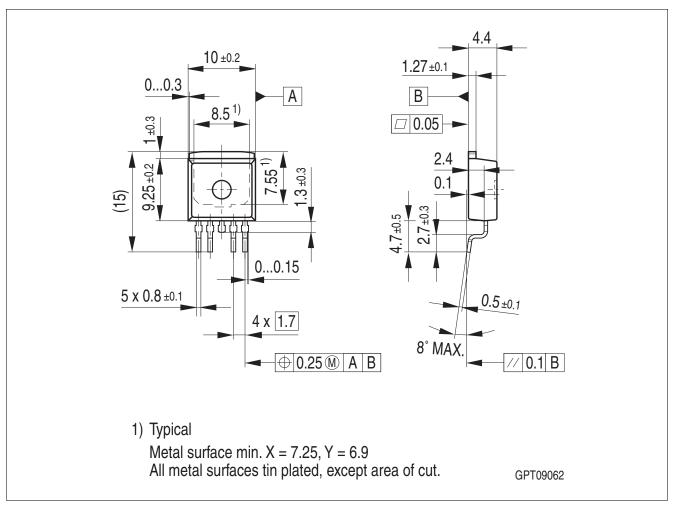


Figure 6: PG-TO263-5-2

#### **Green Product (RoHS compliant)**

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).



## **Revision History**

Revision	Date	Changes
1.21	2012-12-06	Device marking correction on page overview.
1.20	2012-06-27	Remove PG-TO-220-5-12 package on page overview and in package outlines. Added coverpage.
1.1	2009-01-30	RoHS-compliant PG-TO220 and PG-TO263 packages version of the BTS441R All pages: Infineon logo updated Page 1: Added "AEC Qualified" and "RoHS" logo, added "Green Product (RoHS compliant)" and "AEC Qualified" statement to feature list, package names changed to RoHS compliant versions, updated package drawing. Page 12-13: Package names changed to RoHS compliant versions ( PG-TO220-12 and PG-TO263-5-2), added "Green Product" description added Revision History added Legal Disclaimer

Edition 2012-12-06

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